TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7PAU04FU

Dual Inverter (unbuffer) with 3.6 V Tolerant Input

Features

- Low voltage operation: $V_{CC} = 1.8 \sim 3.6 \text{ V}$
- Quiescent supply current: I_{CC} < 20 μA (max)

$$V_{CC} = 3.6 \text{ V}, \text{ Ta} = -40 \sim 85^{\circ}\text{C}$$

• High-speed operation: $t_{pd} = 3.5 \text{ ns (max)} (V_{CC} = 3.0 \sim 3.6 \text{ V})$

$$t_{pd} = 4.2 \text{ ns (max) (VCC} = 2.3 \sim 2.7 \text{ V})$$

$$t_{pd} = 8.4 \text{ ns (max) (V}_{CC} = 1.8 \text{ V})$$

• High-output current: $I_{OH}/I_{OL} = \pm 24 \text{ mA (min) (V}_{CC} = 3.0 \text{ V)}$

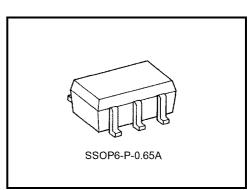
 $I_{OH}/I_{OL} = \pm 18 \text{ mA (min) (V}_{CC} = 2.3 \text{ V)}$

 I_{OH}/I_{OL} = ±6 mA (min) (V_{CC} = 1.8 V)

- Latch-up performance: ±300 mA
- ESD Performance: ±200 V (JEITA)

±2000 V (MIL)

3.6 V tolerant function for input and power down protection are provided.



Weight: 0.0068 g (typ.)

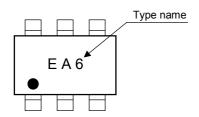
Maximum Ratings (Ta = 25°C)

| Characteristics | Symbol | Rating | Unit |
|------------------------------------|------------------|------------------------------------|------|
| Power supply voltage | V _{CC} | -0.5~4.6 | V |
| DC input voltage | V _{IN} | -0.5~4.6 | V |
| DC output voltage | V _{OUT} | -0.5~V _{CC} + 0.5(Note 1) | V |
| Input diode current | I _{IK} | -50 | mA |
| Output diode current | lok | ±50 (Note 2) | mA |
| DC output current | l _{OUT} | ±50 | mA |
| DC V _{CC} /ground current | I _{CC} | ±100 | mA |
| Power dissipation | PD | 200 | mW |
| Storage temperature | T _{stg} | -65~150 | °C |

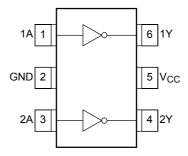
Note 1: Date retention only

Note 2: High or low state. V_{OUT} absolute maximum rating must be observed.

Marking



Pin Assignment (top view)





Logic Diagram

IN A _____ 1 OUT Y

Truth Table

| А | Y |
|---|---|
| L | Н |
| Н | L |

Recommended Operating Conditions

| Characteristics | Symbol | Rating | Unit | |
|--------------------------|----------------------------------|----------------------------|------|--|
| Supply voltage | Vac | 1.8~3.6 | V | |
| Supply voltage | V _{CC} | 1.2~3.6 (Note 3) | V | |
| Input voltage | V _{IN} | -0.3~3.6 | V | |
| Output voltage | V _{OUT} | 0~V _{CC} (Note 4) | ٧ | |
| | I _{OH} /I _{OL} | ±24 (Note 5) | | |
| Output Current | | ±18 (Note 6) | mA | |
| | | ±6 (Note 7) | | |
| Operating temperature | T _{opr} | -40~85 | °C | |
| Input rise and fall time | dt/dv | 0~10 (Note 8) | ns/V | |

Note 3: Date Retention Only

Note 4: High or low state

Note 5: $V_{CC} = 3.0 \sim 3.6 \text{ V}$

Note 6: $V_{CC} = 2.3 \sim 2.7 \text{ V}$

Note 7: $V_{CC} = 1.8 \text{ V}$

Note 8: $V_{CC} = 3.0 \text{ V}$

Electrical Characteristics

DC Characteristics (Ta = -40~85°C)

| Charac | torietice | Symbol | Test Condition | | | Min | Max | Unit |
|--------------------------|------------------------|-------------------------|--|---------------------------|--------------------------|---------------------------|--------------------------|-------|
| Cilarac | teristics | Symbol | | | V _{CC} (V) | IVIIII | IVIAX | Offic |
| "H" level | | | | | 1.8 | 0.85 × V _{CC} | | |
| | | V _{IH} — | | 2.3~3.6 | 0.8 × V _{CC} | _ | V | |
| Input voltage | "L" level | | | 1.8 | _ | 0.15 × V _{CC} | V | |
| | L level | V _{IL} | | _ | 2.3~3.6 | _ | 0.2 × V _{CC} | |
| | | | | $I_{OH} = -100 \mu A$ | 1.8~3.6 | V _{CC} - 0.2 | 1 | |
| | | | | $I_{OH} = -6 \text{ mA}$ | 1.8 | 1.4 | _ | |
| | | | | $I_{OH} = -12 \text{ mA}$ | 2.3 | 1.8 | _ | |
| | "H" level | Voн | V _{IN} = V _{IL} | $I_{OH} = -18 \text{ mA}$ | 2.3 | 1.7 | _ | |
| | | | | $I_{OH} = -12 \text{ mA}$ | 2.7 | 2.2 | | |
| | | | | $I_{OH} = -18 \text{ mA}$ | 3.0 | 2.4 | | |
| Output voltage | | | | $I_{OH} = -24 \text{ mA}$ | 3.0 | 2.2 | _ | V |
| | | | I _{OL} = 100 μA | I _{OL} = 100 μA | 1.8~3.6 | _ | 0.2 | |
| | I _{OH} = 6 mA | $I_{OH} = 6 \text{ mA}$ | 1.8 | _ | 0.3 | | | |
| | | | I _{OL} = 12 mA | $I_{OL} = 12 \text{ mA}$ | 2.3 | _ | 0.4 | |
| | "L" level | V_{OL} | $V_{IN} = V_{IH}$ | I _{OL} = 18 mA | 2.3 | _ | 0.6 | |
| | | | | I _{OL} = 12 mA | 2.7 | _ | 0.4 | |
| | | | I _{OL} = 18 mA | 3.0 | _ | 0.4 | | |
| | | | I _{OL} = 24 mA | 3.0 | _ | 0.55 | | |
| Input leakage curre | nt | I _{IN} | V _{IN} = 0~3.6 V | | 2.7~3.6 | _ | ±5.0 | μΑ |
| Quiescent supply o | urrent | Icc | V _{IN} = V _{CC} or GND | | 2.7~3.6 | _ | 20.0 | ^ |
| Quiescent supply current | | icc | $V_{CC} \le (V_{IN}, V_{OU})$ | T) ≦ 3.6 V | 2.7~3.6 | | ±20.0 | μА |

AC Characteristics (Ta = $-40\sim85^{\circ}$ C, input $t_r = t_f = 2.0$ ns, $C_L = 30$ pF, $R_L = 500$ Ω)

| Characteristics | Symbol | Test Condition | V _{CC} (V) | Min | Max | Unit |
|------------------------|------------------|----------------|---------------------|-----|-----|------|
| | t _{pLH} | (Fig.1, 2) | 1.8 | 1.0 | 8.4 | |
| Propagation delay time | | | 2.5 ± 0.2 | 0.8 | 4.2 | ns |
| | ^t pHL | | 3.3 ± 0.3 | 0.6 | 3.5 | |

For $C_L = pF$, add approximately 300 ps to the Ac maximum specification.

Dynamic Switching Characteristics (Ta = 25°C, input $t_r = t_f = 2.0$ ns, $C_L = 30$ pF)

| Characteristics | Symbol | Test Condition | V _{CC} (V) | Тур. | Unit |
|--|-----------|---|---------------------|-------|------|
| | | $V_{IN} = 1.8 \text{ V}, V_{II} = 0 \text{ V}$ (Note 9) | | 0.25 | |
| | | VIN = 1.0 V, VIL = 0 V (140te 9) | 1.0 | 0.23 | |
| Quiet output maximum dynamic V _{OL} | V_{OLP} | $V_{IN} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$ (Note 9) | 2.5 | 0.6 | ns |
| | | $V_{IN} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$ (Note 9) | 3.3 | 0.8 | |
| | | $V_{IN} = 1.8 \text{ V}, V_{IL} = 0 \text{ V}$ (Note 9) | 1.8 | -0.25 | |
| Quiet output maximum dynamic VOL | V_{OLV} | $V_{IN} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$ (Note 9) | 2.5 | -0.6 | ns |
| | | $V_{IN} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$ (Note 9) | 3.3 | -0.8 | |
| | | $V_{IN} = 1.8 \text{ V}, V_{IL} = 0 \text{ V}$ (Note 9) | 1.8 | 1.5 | |
| Quiet output maximum dynamic VOH | V_{OHP} | $V_{IN} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$ (Note 9) | 2.5 | 1.9 | ns |
| | | $V_{IN} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$ (Note 9) | 3.3 | 2.2 | |

Note 9: Parameter guaranteed by design.

Capacitive Characteristics (Ta = 25°C)

| Characteristics | Symbol | Test Condition | | V _{CC} (V) | Тур. | Unit |
|-------------------------------|-----------------|--------------------------|-----------|---------------------|------|------|
| Input capacitance | C _{IN} | _ | | 1.8, 2.5, 3.3 | 4 | pF |
| Power dissipation capacitance | C _{PD} | f _{IN} = 10 MHz | (Note 10) | 1.8, 2.5, 3.3 | 7 | pF |

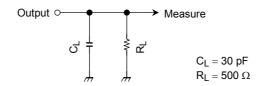
Note 10: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC (opr.)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/2$

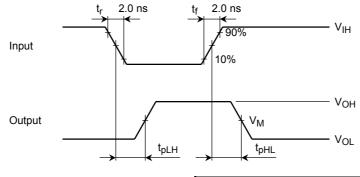
Test Circut

Figure 1



AC Waveform

Figure 2 t_{pLH}, t_{pHL}



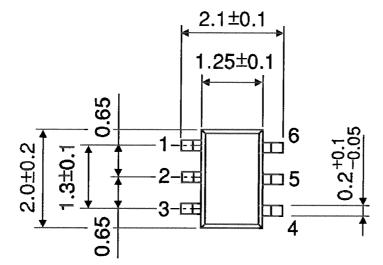
| Symbol | V _{CC} | | | | | |
|----------------|------------------------|-----------------------|--------------------|--|--|--|
| Syllibol | $3.3\pm0.3~\textrm{V}$ | $2.5\pm0.2\textrm{V}$ | 1.8 V | | | |
| V_{IH} | 2.7 V | V _{CC} | V _{CC} | | | |
| V _M | 1.5 V | V _{CC} /2 | V _{CC} /2 | | | |

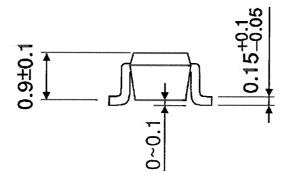
Package Dimensions

SSOP6-P-0.65A

TOSHIBA

Unit: mm





Weight: 0.0068 g (typ.)

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